

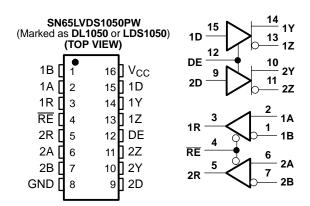
HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

FEATURES

- Typically Meets or Exceeds ANSI TIA/EIA-644-1995 Standard
- Operates From a Single 2.4-V to 3.6-V Supply
- Signaling Rates up to 400 Mbit/s
- Bus-Terminal ESD Exceeds 12 kV
- Low-Voltage Differential Signaling With Typical Output Voltages of 285 mV and a 100- Ω Load
- Propagation Delay Times
 Driver: 1.7-ns Typical
 - Receiver: 3.7-ns Typical
 - Driver: 25-mW Typical
 - Receiver: 60-mW Typical
- Power Dissipation at 200 MHz
 Driver: 25-mW Typical
 - Receiver: 60-mW Typical
- LVTTL Input Levels Are 5-V Tolerant
- Receiver Maintains High Input Impedance
- Receiver Has Open-Circuit Fail Safe
- Available in Thin Shink Outline Packaging With 20-mil Lead Pitch

DESCRIPTION

The SN65LVDS1050 is similar to the SN65LVDS050 except that it is characterized for operation with a lower supply voltage range and packaged in the thin shrink outline package for portable battery-powered applications.



DRIVER FUNCTION TABLE

INPUTS		OUTPUTS			
D	DE	Y Z			
L	Н	L	Н		
Н	Н	Н	L		
Open	Н	L	Н		
Х	L	Z	Z		

H = high level, L = low level, Z = high impedance, X = don't care

RECEIVER FUNCTION TABLE

INPUTS		OUTPUT
$V_{ID} = V_A - V_B$	RE	R
$V_{ID} \ge 100 \text{ mV}$	L	Н
-100 mV < V _{ID} < 100 mV	L	?
$V_{ID} \le -100 \text{ mV}$	L	L
Open	L	Н
Х	Н	Z

H = high level, L = low level, Z = high impedance, X = don't care

The differential line drivers and receivers use low-voltage differential signaling (LVDS) to achieve signaling rates as high as 400 Mbps. The drivers provide a minimum differential output voltage magnitude of 247 mV into a $100-\Omega$ load and receipt of 100-mV signals with up to 1 V of ground potential difference between a transmitter and receiver.

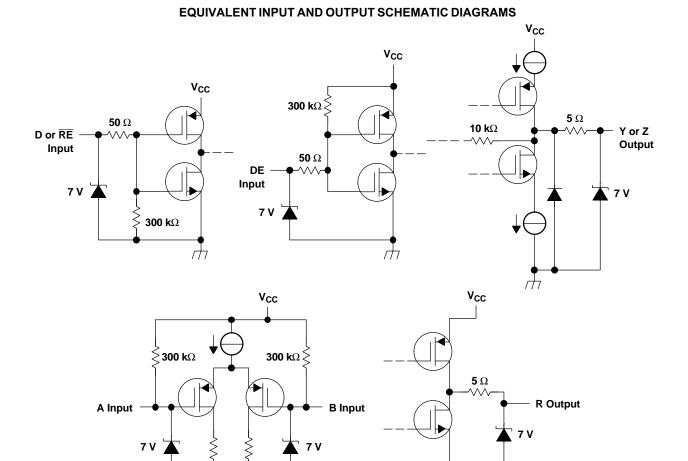
The intended application of this device and signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately $100-\Omega$ characteristic impedance. The transmission media may be printed-circuit board traces, backplanes, or cables. Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment and other application-specific characteristics.

The SN65LVDS1050 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

		UNIT
Supply voltage range, V _{CC} (2	2)	-0.5 V to 4 V
Voltage range (D, R, DE, RE	Voltage range (D, R, DE, RE)	
Voltage range (Y, Z, A, and E	-0.5 V to 4 V	
Electrostatic discharge	Y, Z, A, B , and GND (3)	CLass 3, A:12 kV, B:600 V
	All terminals	Class 3, A:7 kV, B:500 V
Continuous power dissipation	1	See Dissipation Rating Table
Storage temperature range	-65°C to 150°C	
Lead temperature 1,6 mm (1,	/16 inch) from case for 10 seconds	250°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other condition beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages are with respect to network ground terminal.

(3) Tested in accordance with MIL-STD-883C Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	ING DERATING FACTOR ABOVE T _A =85°C POWER RATI T _A =25°C			
PW	774 mW	6.2 mW/°C	402 mW		

RECOMMENDED OPERATING CONDITIONS (1)

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	2.4	2.7	3.6	V
High-level input voltage, V _{IH}	2			V
Low-level input voltage, V _{IL}			0.8	V
Magnitude of differential input voltage, V _{ID}	0.1		0.6	V
Driver output voltage, V_{OY} or V_{OZ}	0		2.4	V
Magnitude of differential output voltage with disabled driver, $ V_{\text{OD}(\text{dis})} $			520	mV
Common-mode input voltage, V _{IC} (see Figure 5)	0		$2.4 - \frac{ V_{ID} }{2}$	V
			V _{CC} -0.8	
Operating free-air temperature, T _A	40	÷	85	°C

(1) The common-mode input voltage, V_{IC} , is not fully 644 compliant when $V_{CC} = 2.4$ V.

DEVICE ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PAR	AMETER	TEST CONDITIONS	MIN	TYP (1)	MAX	UNIT
I _{CC} Supply current	Driver and receiver enabled, No receiver load, Driver $\text{R}_{\text{L}}\text{=}100~\Omega$		12	20		
	Supply current	Driver enabled, Receiver disabled, RL=100 Ω		10	16	mA
		Driver disabled, Receiver enabled, No load		3	6	
		Disabled		0.5	1	

(1) All typical values are at 25°C and with a 2.7-V supply.



DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V _{OD}	Differential output voltage magnitude			247	285	454		
$\Delta V_{OD} $	Change in differential output voltage magnite between logic states	ude	R_L =100 Ω , See Figure 1 and Figure 2	50		50	mV	
V _{OC(SS)}	Steady-state common-mode output voltage			1.125		1.37 5	v	
$\Delta V_{OC(SS)}$	Change in steady-state common-mode outp age between logic states	ut volt-	ut volt- See Figure 3			50	mV	
V _{OC(PP)}	Peak-to-peak common-mode output voltage				50	150	mV	
		DE	\/_ F \/		0.5	20	μA	
IН	High-level input current	D	V _{IH} =5 V		2	20		
		DE			0.5	10		
IIL	Low-level input current	D	V _{IL} =0.8 V		2	20	μA	
			V _{OY} or V _{OZ} =0 V		3	10		
I _{OS}	Short-circuit output current	tput current V _{OD} =0 V		Iort-circuit output current V _{OD} =0 V		3	10	mA
	DE=0 V, V _{OY} =V _{OZ} =0 V							
I _{O(OFF)}	Off-state output current		$\begin{array}{c} {\sf DE=0~V,~V_{OY}=V_{OZ}=0~V} \\ {\sf DE=V_{CC},~V_{OY}=V_{OZ}=0~V,} \\ {\sf V_{CC}<1.5~V} \end{array}$	-1		1	μA	
C _{IN}	Input capacitance				3		pF	

RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAN	IETER	TEST CONDITIONS	MIN	TYP (1)	MAX	UNIT
V _{ITH+}	Positive-going differential input voltage threshold	Cas Figure 5 and Table 4			100	
V _{ITH-}	Negative-going differential input voltage threshold	See Figure 5 and Table 1	100			mV
V _{OH}	High-level output voltage	I _{OH} =-8 mA	2			V
V _{OL}	Low-level output voltage	I _{OL} =8 mA			0.4	V
	Input current (A or B inputs)	V _I =0	2		20	
II.		V _I =2.4 V	1.2			μA
I _{I(OFF)}	Power-off input current (A or B inputs)	V _{CC} =0			±20	μA
I _{IH}	High-level input current (enables)	V _{IH} =5 V			±10	μA
I _{IL}	Low-level input current (enables)	V _{IL} =0.8 V			±10	μA
l _{oz}	High-impedance output current	V _O =0 or 5 V			±10	μA

(1) All typical values are at 25° C and with a 2.7-V supply.



DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP (1)	М	AXUNIT
t _{PLH}	Propagation delay time, low-to-high-level output	R _L =100Ω, C _L =10 pF, See Figure 2		1.7	2. 7	ns
t _{PHL}	Propagation delay time, high-to-low-level output			1.7	3	ns
t _r	Differential output signal rise time			0.8	1	ns
t _f	Differential output signal fall time			0.8	1	ns
t _{sk(p)}	Pulse skew (t _{pHL} - t _{pLH})			300		ps
t _{sk(o)}	Channel-to-channel output skew (2)			150		ps
t _{en}	Enable time	See Figure 4		7.8	10	ns
t _{dis}	Disable time	See Figure 4		6.6	10	ns

 $\begin{array}{ll} \mbox{(1)} & \mbox{All typical values are at 25°C and with a 2.7-V supply.} \\ \mbox{(2)} & t_{sk(o)} \mbox{ is the maximum delay time difference between drivers on the same device.} \end{array}$

RECEIVER SWITCHING CHARCTERISTICS

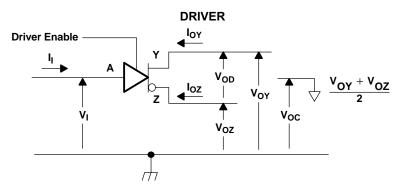
over recommended operating conditions (unless otherwise noted)

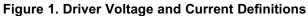
PARAN	IETER	TEST CONDITIONS	MIN	TYP (1)	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output	C _L =10 pF, See Figure 6		3.7	5.2	ns
t _{PHL}	Propagation delay time, high-to-low-level output			3.7	4.5	ns
t _{sk(p)}	Pulse skew (t _{pHL} - t _{pLH})			0.3		ns
t _r	Output signal rise time			0.8	1.5	ns
t _f	Output signal fall time			0.8	1.5	ns
t _{PZH}	Propagation delay time, high-level-to-high-impedance output			5.4		ns
t _{PZL}	Propagation delay time, low-level-to-low-impedance output	See Figure 7		6.3		ns
t _{PHZ}	Propagation delay time, high-impedance-to-high-level output			6.1		ns
t _{PLZ}	Propagation delay time, low-impedance-to-high-level output			6.9		ns

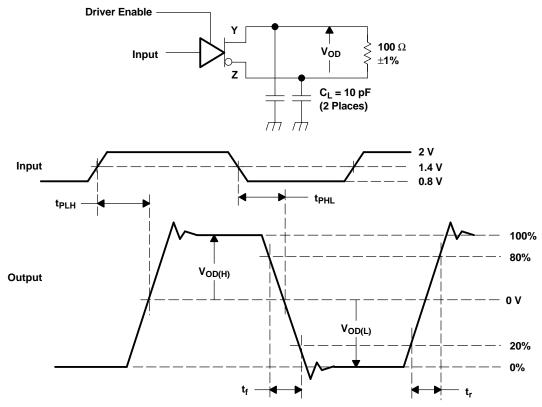
(1) All typical values are at 25° C and with a 2.7-V supply.



PARAMETER MEASUREMENT INFORMATION



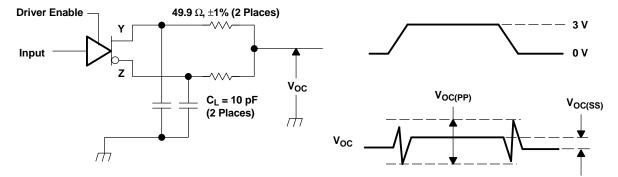




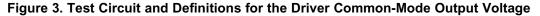
All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 \pm 0.2 ns . C_1 includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

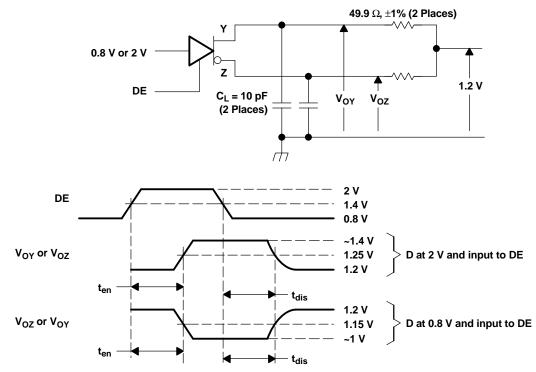
Figure 2. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal





All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns . C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T. The measurement of V_{OC(PP)} is made on test equipment with a -3 dB bandwidth of at least 300 MHz.

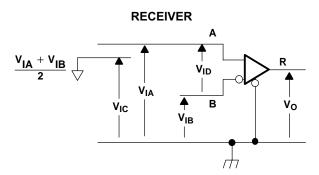




All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns . C_1 includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

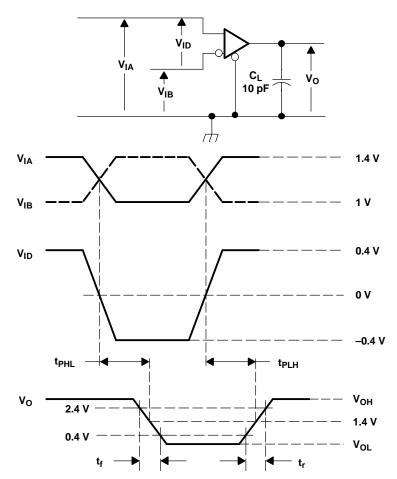
Figure 4. Driver Enable and Disable Time Circuit and Definitions





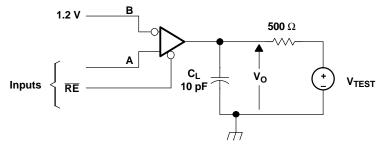
APPLIED VOLTAGES (V)		RESULTING DIFFERENTIAL INPUT VOLTAGE (mV)	RESULTING COMMON-MODE INPUT VOLTAGE (V)				
V _{IA} V _{IB}		V _{ID}	V _{IC}				
1.25	1.15	100	1.2				
1.15	1.25	100	1.2				
2.4	2.3	100	2.35				
2.3	2.4	100	2.35				
0.1	0	100	0.05				
0	0.1	100	0.05				
1.5	0.9	600	1.2				
0.9	1.5	600	1.2				
2.4	1.8	600	2.1				
1.8	2.4	600	2.1				
0.6	0	600	0.3				
0	0.6	600	0.3				





All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

Figure 6. Timing Test Circuit and Waveforms



All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

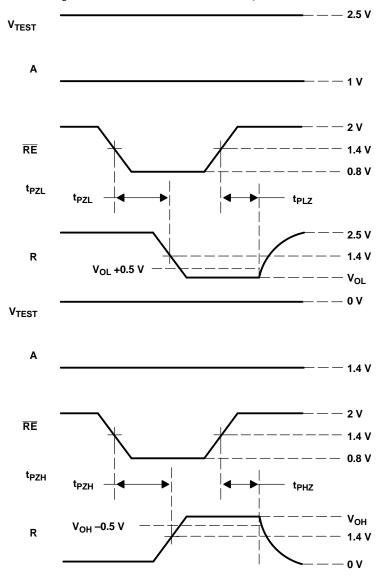
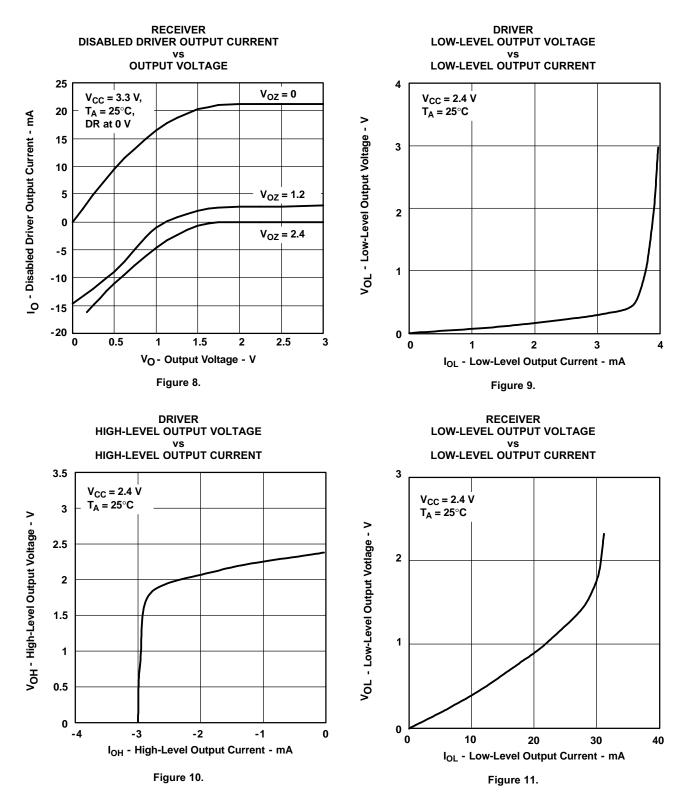


Figure 7. Enable/Disable Time Test Circuit and Waveforms

TYPICAL CHARACTERISTICS





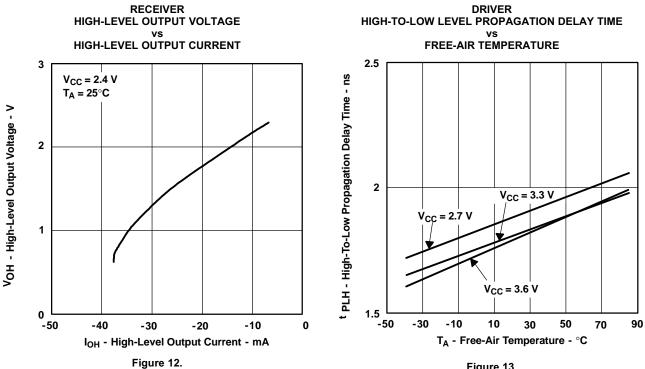
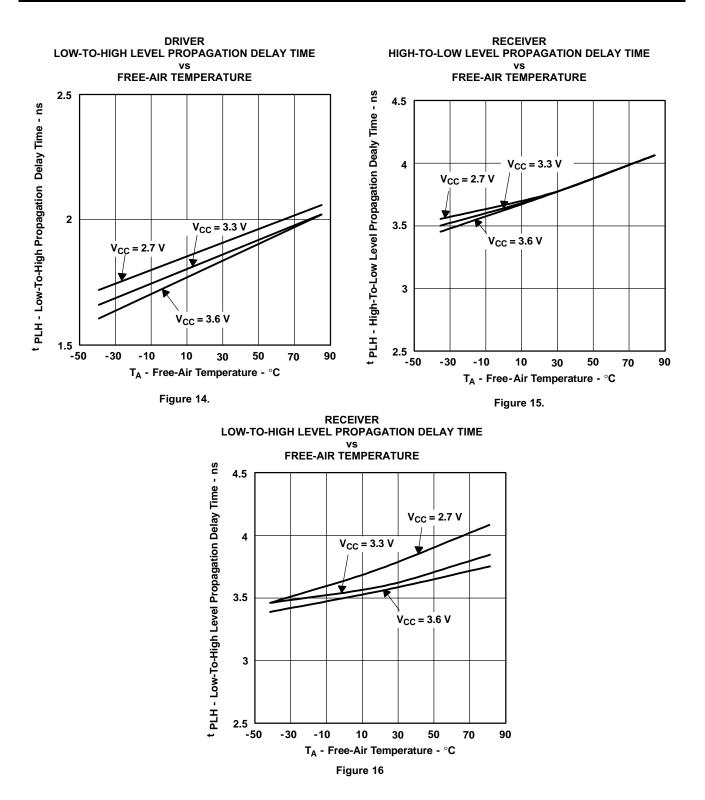


Figure 13.







APPLICATION INFORMATION

The devices are generally used as building blocks for high-speed point-to-point data transmission. Ground differences are less than 1 V with a low common-mode output and balanced interface for very low noise emissions. Devices can interoperate with RS-422, PECL, and IEEE-P1596. Drivers/Receivers maintain ECL speeds without the power and dual supply requirements.

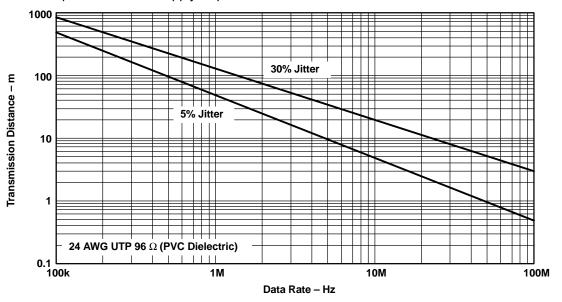


Figure 17. Data Transmission Distance Versus Rate

Fail Safe

One of the most common problems with differential signaling applications is how the system responds when no differential voltage is present on the signal pair. The LVDS receiver is like most differential line receivers, in that its output logic state can be indeterminate when the differential input voltage is between -100 mV and100 mV and within its recommended input common-mode voltage range. TI's LVDS receiver is different in how it handles the open-input circuit situation, however.

Open-circuit means that there is little or no input current to the receiver from the data line itself. This could be when the driver is in a high-impedance state or the cable is disconnected. When this occurs, the LVDS receiver pulls each line of the signal pair to near V_{CC} through 300-k Ω resistors as shown in Figure 11. The fail-safe feature uses an AND gate with input voltage thresholds at about 2.3 V to detect this condition and force the output to a high-level, regardless of the differential input voltage.

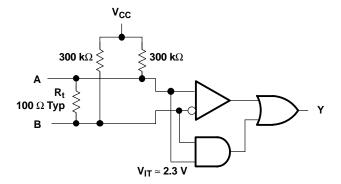


Figure 18. Open-Circuit Fail Safe of the LVDS Receiver

It is only under these conditions that the output of the receiver is valid with less than a 100-mV differential input voltage magnitude. The presence of the termination resistor, Rt, does not affect the fail-safe function as long as it is connected as shown in the figure. Other termination circuits may allow a dc current to ground that could defeat the pullup currents from the receiver and the fail-safe feature.



6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN65LVDS1050PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	DL1050	Samples
SN65LVDS1050PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	DL1050	Samples
SN65LVDS1050PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	DL1050	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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6-Feb-2020

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVDS1050PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVDS1050PWR	TSSOP	PW	16	2000	367.0	367.0	35.0

PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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